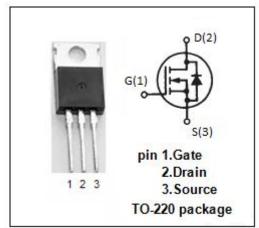


isc N-Channel MOSFET Transistor

DMT6009LCT

FEATURES

- Drain Current –I_D= 37.2A@ T_C=25°C
- · Drain Source Voltage-
 - : V_{DSS}= 60V(Min)
- Static Drain-Source On-Resistance
 - : $R_{DS(on)} = 12m \Omega (Max)$
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



DESCRIPTION

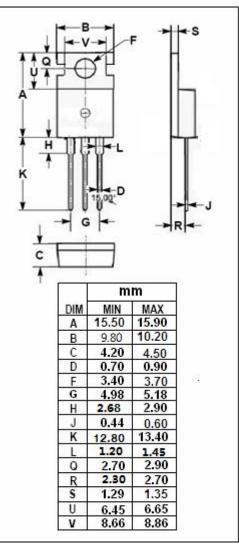
 Designed for use in switch mode power supplies and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| 1 = 2 = 2 = 1 = 1 = 1 = 1 = 1 = 2 = 3 1 = 2 = 3 | | | | | | |
|---------------------------------------------------|----------------------------------------|-----------------|------------|--|--|--|
| SYMBOL | PARAMETER | VALUE | UNIT | | | |
| V _{DSS} | Drain-Source Voltage | 60 | V | | | |
| V _{GS} | Gate-Source Voltage-Continuous | ±16 | V | | | |
| I _D | Drain Current-Continuous 37.2 | | А | | | |
| I _{DM} | Drain Current-Single Pluse 80 | | А | | | |
| P _D | Total Dissipation @T _C =25℃ | 25 | W | | | |
| TJ | Max. Operating Junction Temperature | erature -55~150 | | | | |
| T _{stg} | Storage Temperature | -55~150 | $^{\circ}$ | | | |

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|---------------------|--------------------------------------|-----|------|
| R _{th j-c} | Thermal Resistance, Junction to Case | 5.0 | °C/W |





isc N-Channel MOSFET Transistor

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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | MAX | UNIT |
|----------------------|---------------------------------|-------------------------------------------------------------|-----|------|------|
| V _{(BR)DSS} | Drain-Source Breakdown Voltage | V _{GS} = 0; I _D = 0.25mA | 60 | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} = V _{GS} ; I _D = 0.25mA | 0.7 | 2.0 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} = 10V; I _D = 13.5A | | 12 | mΩ |
| lgss | Gate-Body Leakage Current | V _{GS} = ±16V;V _{DS} = 0 | | ±100 | nA |
| I _{DSS} | Zero Gate Voltage Drain Current | V _{DS} = 48V; V _{GS} = 0 | | 1.0 | μА |
| V _{SD} | Forward On-Voltage | I _S = 20A; V _{GS} = 0 | | 1.2 | V |

NOTICE:

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